90 Watt Transistor offers High Efficiency and High Gain

8/15/2019 – San Jose, California: RFMW announces design and sales support for a high gain, GaN transistor with excellent efficiency. The Qorvo QPD0060 spans DC to 2.7 GHz with 90 Watts of P3dB output power and maximum drain efficiency of 74.7%. Linear gain is 19.5 dB and efficiency-tuned P3dB gain is 21.5 dB. Designed for 48 V operation, the QPD0060 serves wireless infrastructure, active antenna systems, military & commercial radar, land mobile and military radio communications and test instrumentation. Functional as either a driver or final stage it’s both CW and pulse capable. Offered in a plastic overmold, SMT package.

Samples are available for qualified requirements through RFMW at 1-877-FOR RFMW (367-7369) within North America; or please find your local sales engineer (worldwide) at the contact page on the RFMW web site.

About RFMW

RFMW is a specialty electronics distribution company focused exclusively on serving customers that require RF and microwave components and semiconductors, as well as component engineering support. The company continues to expand its list of products from selective suppliers with RF/microwave expertise. RFMW deploys a highly experienced, technically skilled team to assist customers with component selection and fulfillment.

To learn more about RFMW, visit their Website at www.rfmw.com, or call us at 1.877.FOR.RFMW (367-7369), or via e-mail at info@rfmw.com.

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